FAIRCHILD

SEMICONDUCTOR®

FJPF5321

High Voltage and High Reliability

- High speed Switching
- Wide Safe Operating Area



NPN Triple Diffused Planar Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
/ _{СВО}	Collector-Base Voltage	800	V
/ _{CEO}	Collector-Emitter Voltage	500	V
/ _{EBO}	Emitter-Base Voltage	7	V
С	Collector Current (DC)	5	А
CP	*Collector Current (Pulse)	10	А
В	Base Current (DC)	2	А
BP	*Base Current (Pulse)	4	А
°c	Power Dissipation(T _C =25°C)	40	W
J	Junction Temperature	150	°C
STG	Storage Temperature	- 55 ~ 150	°C

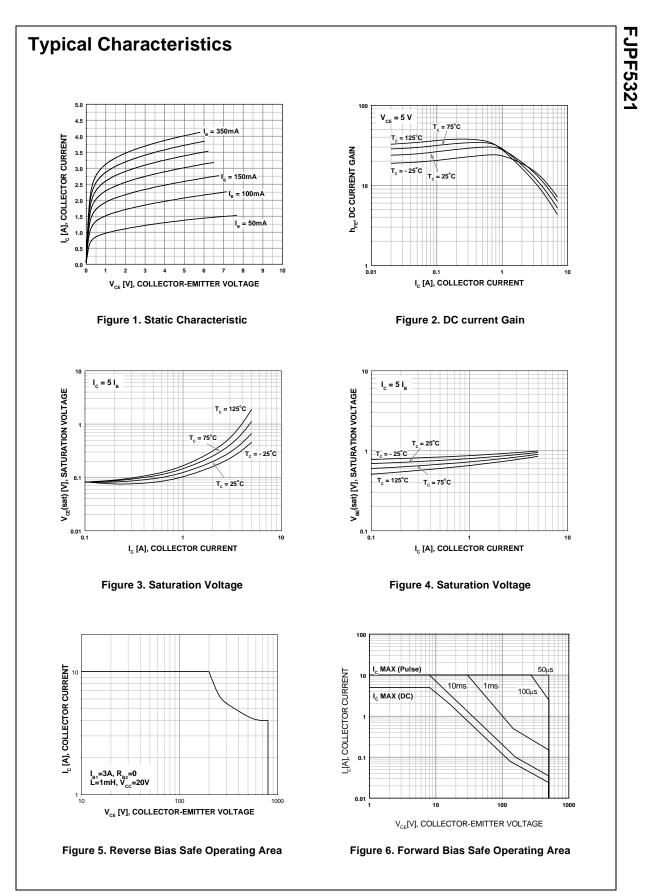
Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = 1mA, I _E = 0	800	-	-	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA, I _B = 0	500	-	-	V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{\rm C} = 1$ mA, $I_{\rm C} = 0$	7	-	-	V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 800 V, I_E = 0$	-	-	100	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 7V, I_{C} = 0$	-	-	10	μΑ
h _{FE1}	DC Current Gain	V _{CE} = 5V, I _C = 0.6A	15	-	40	
h _{FE2}		$V_{CE} = 5V, I_{C} = 3A$	8	-	-	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 3A, I _B = 0.6A	-	-	1.0	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 3A, I _B = 0.6A	-	-	1.5	V
f _T	Current Gain bandwidth Product	$V_{CE} = 10V, I_{C} = 0.6A$	-	14	-	MHz
C _{ob}	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 1MHz$	-	65	100	pF
C _{ib}	Input Capacitance	$V_{EB} = 7V, I_{C} = 0, f = 1MHz$	-	1400	2000	pF
t _{ON}	Turn On Time	V _{CC} = 125V, I _C = 1A	-	-	0.5	μs
t _{STG}	Storage Time	Ι _{B1} = -Ι _{B2} = 0.2Α		-	6.5	μs
t _F	Fall Time	$R_L = 125\Omega$	-	-	0.3	μs
t _{ON}	Turn On Time	$V_{CC} = 250V, I_{C} = 4A$	-	-	0.5	μs
t _{STG}	Storage Time	I _{B1} = 0.8A, I _{B2} = -1.6A	-	-	3.0	μs
t _F	Fall Time	$R_L = 62.5\Omega$	-	-	0.3	μs

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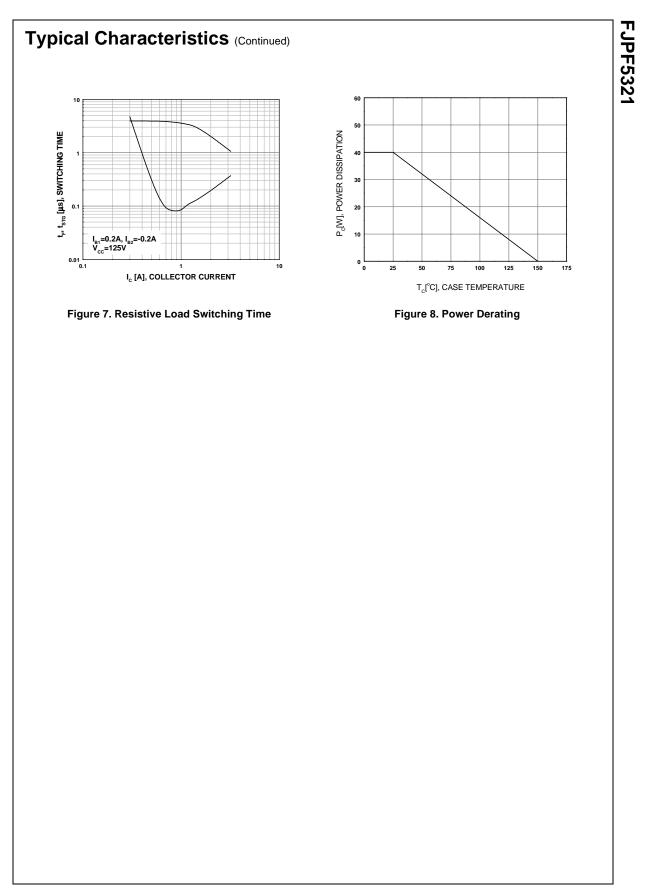
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Symbol		Characteristics	Rating	Unit
ic	Thermal Resistance	Junction to Case	3.1	°C/W
a		Junction to Ambient	62.5	Ţ



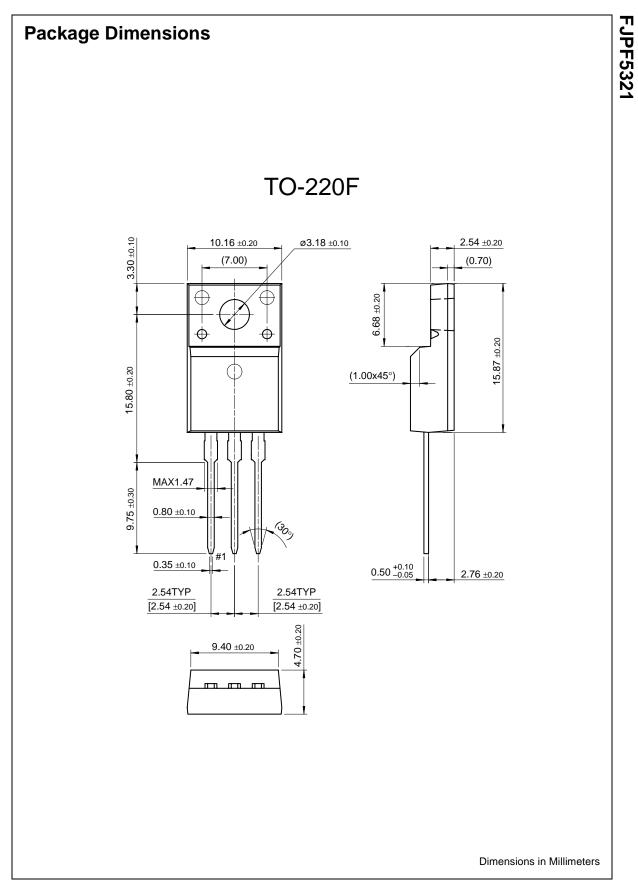
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